

Title: TRANSISTORS, POWER, MOSFET, P-CHANNEL, RAD-HARD BASED ON TYPE STRH40P10

Number: 5205/025

Issue: 4

Page: 11

Paragraph: 2.5.2 High and Low Temperatures Electrical Measurements

Original wording: See document in attachment.

Proposed wording: See document in attachment.

Justification: See document an attachment.

STMicroelectronics would like harmonize the VSD maximum limits for high temperature between products of the same type (P-channel). STMicroelectronics propose the new limit for the STRH40P10 product in the table below. These new limits cover the current detail specification without any impact for the customer and the products already delivered.

			Pre Radiation +125°C
Product	Line	ESCC	VSD (V) max Current to New
STRH40N6	HG6F	5205024	1.275
STRH100N6	HG6K	5205022	1.275
STRH100N10	HG0K	5205021	1.275
STRH8N10	HG0C	5205023	1.275
STRH12P10	HP0D	5205029	-1.25
STRH40P10	HPOJ	5205025	-0.95 to -1.25